



HIGH VOLTAGE POWER SCHOTTKY RECTIFIER

Product Summary

| V _{RRM} (V) | I _O (A) | V _{F (MAX)} (V) @ +25°C | I _{R (MAX)} (mA) @ +25°C |
|----------------------|--------------------|-------------------------------------|--------------------------------------|
| 200 | 2x5 | 0.95 | 0.15 |

Description

High voltage dual Schottky rectifier suited for switch mode power supplies and other power converters. This device is intended for use in medium voltage operation, and particularly, in high frequency circuits where low switching losses and low noise are required.

MBR10200C is available in TO-220-3 (2) and TO-220F-3 (Option 1) packages.

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Features

- Low Forward Voltage: 0.95V @ +25°C
- High Surge Capacity
- +150°C Operating Junction Temperature
- 10A Total (5A Per Diode Leg)
- Guard-Ring for Stress Protection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: TO-220-3 and TO-220F-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Polarity: See Below
- Weight: TO-220-3 (2) 1.95 grams (Approximate)

TO-220F-3 (Option 1) – 1.69 grams (Approximate)

TO-220-3 (2)



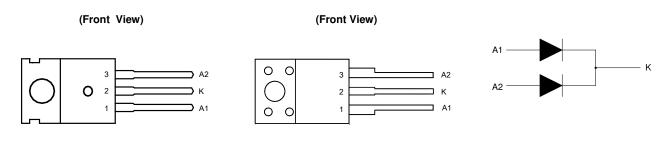
TO-220F-3 (Option 1)



Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments



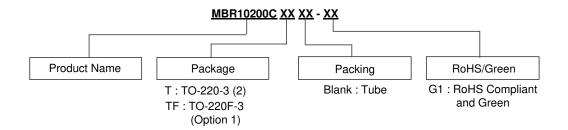
TO-220-3 (2)

TO-220F-3 (Option 1)

Internal Structure of MBR10200C



Ordering Information (Note 4)



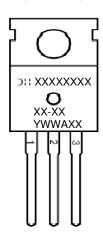
| Package | Part Number | Marking ID | Packing |
|----------------------|----------------|----------------|----------------|
| TO-220-3 (2) | MBR10200CT-G1 | MBR10200CT-G1 | 50 Pieces/Tube |
| TO-220F-3 (Option 1) | MBR10200CTF-G1 | MBR10200CTF-G1 | 50 Pieces/Tube |

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

(1) TO-220-3 (2)

(Front View)



☐ H = Manufacturer's Marking

First and Second Lines: Logo and Marking ID (See

Ordering Information) Third Line: Date Code

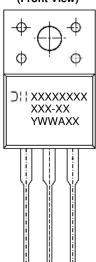
Y: Year

WW: Work Week of Molding

A: Assembly House Code XX: 7th and 8th Digits of Batch Number

TO-220F-3 (Option 1)

(Front View)



☐ Hanufacturer's Marking

First and Second Lines: Logo and Marking ID (See

Ordering Information) Third Line: Date Code

Y: Year

WW: Work Week of Molding

A: Assembly House Code

XX: 7th and 8th Digits of Batch Number



Maximum Ratings (Each Diode Leg)

| Characteristic | Symbol | Rating | Unit |
|--|--|-------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 200 | V |
| Average Rectified Forward Current (Rated V_R) $T_C = +140$ °C | I _{F(AV)} | 5 | Α |
| Peak Repetitive Forward Current (Rated V_R , Square Wave, 20kHz) $T_C = +138^{\circ}C$ | I _{FRM} | 10 | Α |
| Non Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Half Wave, Single Phase, 60Hz) | I _{FSM} | 100 | А |
| Operating Junction Temperature (Note 5) | TJ | +150 | °C |
| Storage Temperature Range | T _{STG} | -50 to +150 | °C |
| Voltage Rate of Change (Rated V _R) | dv/dt | 10000 | V/µs |
| ESD (Machine Model = C) | _ | >400 | V |
| ESD (Human Body Model = 3B) | _ | >8000 | V |

Notes: 5. The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_D/dT_J < 1/\theta_{JA}$.

Thermal Characteristics

| Characteristic | Symbol | Rating | | Unit | |
|--|-----------------|----------------------|-----|--------|--|
| Maximum Thermal Resistance (Junction to Case) | Б | TO-220-3 (2) | 3.0 | 2011 | |
| (Note 6) | $R_{\theta JC}$ | TO-220F-3 (Option 1) | 4.5 | °C/W | |
| Maximum Thermal Resistance (Junction to Ambient) | В | TO-220-3 (2) | 60 | °C/W | |
| (Note 6) | $R_{\theta JA}$ | TO-220F-3 (Option 1) | 60 | - C/VV | |

Note: 6. Device mounted on heat sink, with minimum recommended pad layout per http://www.diodes.com/package-outlines.html.

Electrical Characteristics (Each Diode Leg)

| Characteristic | Symbol | Rating | Unit | Test Condition |
|--|----------------|--------|------|---|
| Maximum Instantaneous Forward Voltage Drop | V _F | 0.95 | V | $I_F = 5A$, $T_C = +25^{\circ}C$ |
| (Note 7) | | 0.85 | | $I_F = 5A$, $T_C = +125^{\circ}C$ |
| M : 1 : 1 : 1 : 2 | I _R | 0.15 | mA | Rated DC Voltage, T _C = +25°C |
| Maximum Instantaneous Reverse Current (Note 7) | | 15 | | Rated DC Voltage, T _C = +125°C |

Note: 7. Short duration pulse test used to minimize self-heating effect, Pulse Test Width = $300\mu s$, Duty Cycle < 2.0%.



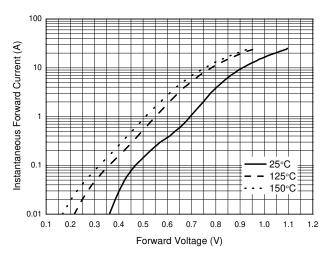


Figure 1. Typical Forward Voltage Per Diode

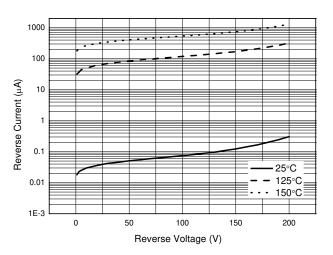


Figure 2. Typical Reverse Current Per Diode

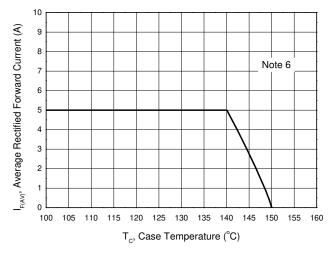


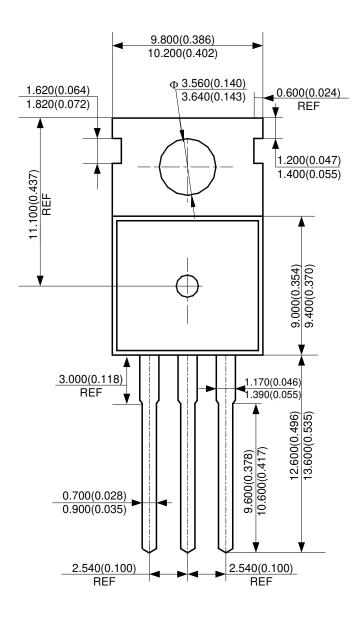
Figure 3. Average Rectified Forward Current vs.
Case Temperature (Per Diode)

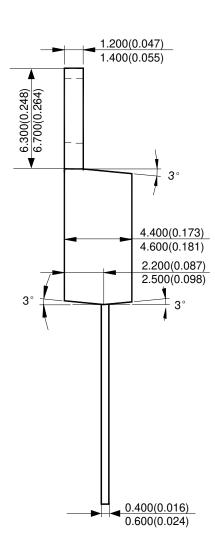


Package Outline Dimensions (All dimensions in mm(inch).)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: TO-220-3 (2)



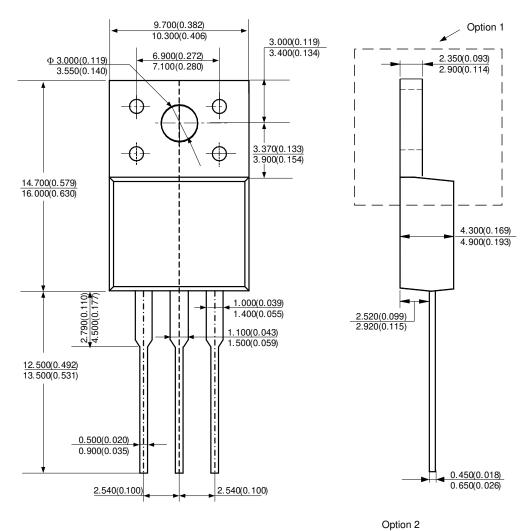


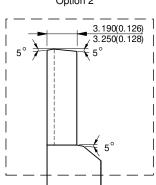


Package Outline Dimensions (All dimensions in mm(inch).) (continued)

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(2) Package Type: TO-220F-3 (Option 1)







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